TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VCX157FT, TC74VCX157FK

Low Voltage Quad 2-Channel Multiplexer with 3.6 V Tolerant Inputs and Outputs

The TC74VCX157 is a high performance CMOS multiplexer which is guaranteed to operate from 1.2-V to 3.6-V. Designed for use in 1.5 V, 1.8 V, 2.5 V or 3.3 V systems, it achieves high. speed operation while maintaining the CMOS low power dissipation.

It is also designed with over voltage tolerant inputs and outputs up to 3.6 V.

It consists of four 2-input digital multiplexers with common select and strobe inputs.

When the \overline{ST} input is held "H" level, selection of data is inhibited and all the outputs become "L" level. The SELECT decoding determines whether the A or B inputs get routed to their corresponding Y outputs.

All inputs are equipped with protection circuits against static discharge.

Features

- Low voltage operation: V_{CC} = 1.2 to 3.6 V
- High speed operation: $t_{pd} = 3.0 \text{ ns (max) (V}_{CC} = 3.0 \text{ to } 3.6 \text{ V)}$

 $t_{pd} = 3.5 \text{ ns (max) (V}_{CC} = 2.3 \text{ to } 2.7 \text{ V})$

 $t_{pd} = 7.0 \text{ ns (max) (V}_{CC} = 1.65 \text{ to } 1.95 \text{ V})$

 $t_{pd} = 14.0 \text{ ns (max) (V}_{CC} = 1.4 \text{ to } 1.6 \text{ V})$

 $t_{pd} = 35.0 \text{ ns (max) (VCC} = 1.2 \text{ V)}$

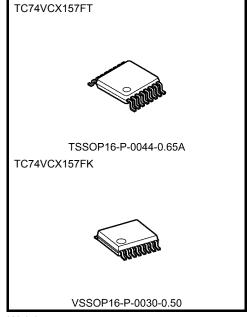
- 3.6 V tolerant inputs and outputs.
- Output current: $I_{OH}/I_{OL} = \pm 24 \text{ mA (min)} (V_{CC} = 3.0 \text{ V})$

 $I_{OH}/I_{OL} = \pm 18 \text{ mA (min) (V}_{CC} = 2.3 \text{ V)}$

 $I_{OH}/I_{OL} = \pm 6 \text{ mA (min)} (V_{CC} = 1.65 \text{ V})$

 $I_{OH}/I_{OL} = \pm 2 \text{ mA (min)} (V_{CC} = 1.4 \text{ V})$

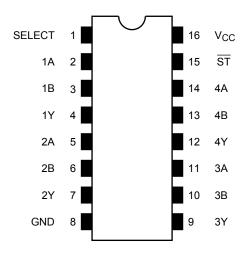
- Latch-up performance: -300 mA
- ESD performance: Machine model $\geq \pm 200 \text{ V}$ Human body model $\geq \pm 2000 \text{ V}$
- Package: TSSOP and VSSOP (US)
- Power down protection is provided on all inputs and outputs.



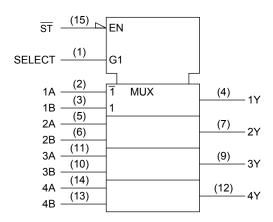
Weight

TSSOP16-P-0044-0.65A : 0.06 g (typ.) VSSOP16-P-0030-0.50 : 0.02 g (typ.)

Pin Assignment (top view)



IEC Logic Symbol

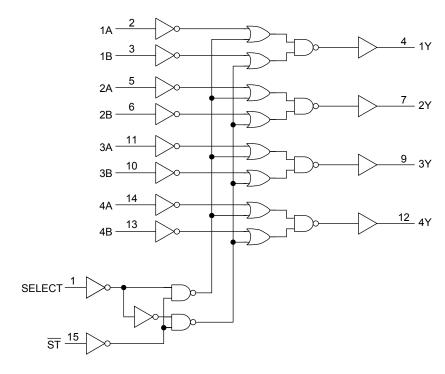


Truth Table

	Inputs							
ST	SELECT	Α	В	Υ				
Н	Х	Х	Х	L				
L	L	L	Х	L				
L	L	Н	Х	Н				
L	Н	Х	L	L				
L	Н	Х	Н	Н				

X: Don't care

System Diagram



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	V _{CC}	-0.5 to 4.6	V
DC input voltage	V _{IN}	-0.5 to 4.6	V
		-0.5 to 4.6 (Note 2)	
DC output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5 (Note 3)	V
Input diode current	I _{IK}	-50	mA
Output diode current	lok	±50 (Note 4)	mA
DC output current	lout	±50	mA
Power dissipation	PD	180	mW
DC V _{CC} /ground current	I _{CC} /I _{GND}	±100	mA
Storage temperature	T _{stg}	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

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Note 2: $V_{CC} = 0 V$

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: $V_{OUT} < GND, V_{OUT} > V_{CC}$



Operating Ranges (Note 1)

Characteristics	Symbol	Rating	Unit	
Supply voltage	V_{CC}	1.2 to 3.6	V	
Input voltage	V _{IN}	-0.3 to 3.6	V	
Output voltage	Vout	0 to 3.6 (Note 2)	V	
Output voltage	VOU1	0 to V _{CC} (Note 3)	V	
		±24 (Note 4)		
Output ourrent	la/la.	±18 (Note 5)		
Output current	I _{OH} /I _{OL}	±6 (Note 6)	mA	
		±2 (Note 7)		
Operating temperature	T _{opr}	-40 to 85	°C	
Input rise and fall time	dt/dv	0 to 10 (Note 8)	ns/V	

Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.

Note 2: $V_{CC} = 0 V$

Note 3: High or low state

Note 4: $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$

Note 5: $V_{CC} = 2.3$ to 2.7 V Note 6: $V_{CC} = 1.65$ to 1.95 V

Note 7: $V_{CC} = 1.4 \text{ to } 1.6 \text{ V}$

Note 8: $V_{IN} = 0.8$ to 2.0 V, $V_{CC} = 3.0$ V

Electrical Characteristics

DC Characteristics (Ta = -40 to 85° C, 2.7 V < $V_{CC} \le 3.6$ V)

Characteristics		Symbol	Test Condition			Min	Max	Unit
		Oymbor	rest condition		V _{CC} (V)	IVIIII	IVICX	Onic
Input voltage	High level	V _{IH}		_	2.7 to 3.6	2.0	_	V
iliput voltage	Low level	V _{IL}		_	2.7 to 3.6		0.8	V
High lev				I _{OH} = -100 μA	2.7 to 3.6	V _{CC} - 0.2	_	
	High level	Voh	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -12 mA	2.7	2.2	_	
				$I_{OH} = -18 \text{ mA}$	3.0	2.4	_	V
				$I_{OH} = -24 \text{ mA}$	3.0	2.2	_	
	Low level		$V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 100 \mu A$	2.7 to 3.6		0.2	
		V _{OL}		$I_{OL} = 12 \text{ mA}$	2.7		0.4	
	LOW level			$I_{OL} = 18 \text{ mA}$	3.0		0.4	
				$I_{OL} = 24 \text{ mA}$	3.0		0.55	
Input leakage curre	nt	I _{IN}	V _{IN} = 0 to 3.6 V		2.7 to 3.6		±5.0	μΑ
Power off leakage of	current	I _{OFF}	V_{IN} , $V_{OUT} = 0$ to 3.6 \	/	0		10.0	μΑ
Ouissant supply suppl		loo	V _{IN} = V _{CC} or GND		2.7 to 3.6		20.0	
Quiescent supply of	unent	Icc	V _{CC} ≤ V _{IN} ≤ 3.6 V		2.7 to 3.6		±20.0	μΑ
Increase in I _{CC} per	input	Δl _{CC}	$V_{IH} = V_{CC} - 0.6 V$		2.7 to 3.6		750	



DC Characteristics (Ta = -40 to 85°C, 2.3 V \leq V_{CC} \leq 2.7 V)

Character	ietice	Symbol	Test Condition			Min	Max	Unit
Ondidotensties		Cymbol	rest Schalash		V _{CC} (V)	IVIIII	IVIAX	Onit
Input voltage	High level	V _{IH}	_	_	2.3 to 2.7	1.6	_	V
input voitage	Low level	V _{IL}	_	_	2.3 to 2.7	_	0.7	V
				I _{OH} = -100 μA	2.3 to 2.7	V _{CC} - 0.2	_	
	High level	Voh	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -6 mA	2.3	2.0	_	
				I _{OH} = -12 mA	2.3	1.8	_	V
Output voltage				I _{OH} = -18 mA	2.3	1.7	_	
			V _{IN} = V _{IH} or V _{IL}	$I_{OL} = 100 \mu A$	2.3 to 2.7	_	0.2	
	Low level	V _{OL}		I _{OL} = 12 mA	2.3	_	0.4	
				I _{OL} = 18 mA	2.3	_	0.6	
Input leakage curre	ent	I _{IN}	V _{IN} = 0 to 3.6 V	•	2.3 to 2.7	_	±5.0	μА
Power off leakage	current	l _{OFF}	V _{IN} , V _{OUT} = 0 to 3.6 V		0	_	10.0	μА
Quiogoant gunnly o	urront	laa	V _{IN} = V _{CC} or GND		2.3 to 2.7	_	20.0	^
Quiescent supply c	urrent	Icc	V _{CC} ≤ V _{IN} ≤ 3.6 V		2.3 to 2.7	_	±20.0	μА

DC Characteristics (Ta = -40 to 85° C, 1.65 V \leq V_{CC} < 2.3 V)

Characteristics		Symbol	Test C	ondition	_	Min	Max	Unit
		- ,						
Input voltage	High level	V _{IH}	-	_	1.65 to 2.3	0.65 × V _{CC}	_	V
input voitage	Low level	V _{IL}	-	_			0.2 × V _{CC}	V
High level	High level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -100 μA	1.65 to 2.3	V _{CC} - 0.2	_	V
Output voltage				I _{OH} = -6 mA	1.65	1.25	_	
	Low level	V _{OL}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 100 \ \mu A$	1.65 to 2.3	_	0.2	
	Low level			I _{OL} = 6 mA	1.65	_	0.3	
Input leakage curre	nt	I _{IN}	V _{IN} = 0 to 3.6 V		1.65 to 2.3	_	±5.0	μА
Power off leakage of	urrent	l _{OFF}	V _{IN} , V _{OUT} = 0 to 3.6 V		0	_	10.0	μА
Outroport supply support		Icc	V _{IN} = V _{CC} or GND		1.65 to 2.3	_	20.0	
Quiescent supply co	Quiescent supply current		V _{CC} ≤ V _{IN} ≤ 3.6 V		1.65 to 2.3	_	±20.0	μА



DC Characteristics (Ta = -40 to 85°C, 1.4 V \leq V_{CC} \leq 1.65 V)

Characteris	Characteristics		Test Co	ondition	1	Min	Max	Unit
		Symbol						
Input voltage	High level	V _{IH}	_	-	1.4 to 1.65	0.65 × V _{CC}		V
Low level		V _{IL}	_		1.4 to 1.65	ı	0.05 × V _{CC}	•
High	High level	ligh level V _{OH}	$V_{IN} = V_{IH}$ or V_{IL}	I _{OH} = -100 μA	1.4 to 1.65	V _{CC} - 0.2	_	V
Output voltage				$I_{OH} = -2 \text{ mA}$	1.4	1.05	_	
	Low level	Vai	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 100 \mu A$	1.4 to 1.65	_	0.05	
	Low level	V _{OL}		I _{OL} = 2 mA	1.4	_	0.35	
Input leakage curre	nt	I _{IN}	V _{IN} = 0 to 3.6 V		1.4 to 1.65		±5.0	μΑ
Power off leakage of	urrent	loff	V _{IN} , V _{OUT} = 0 to 3.6 V		0		10.0	μΑ
Quiescent supply cu	0.:		V _{IN} = V _{CC} or GND		1.4 to 1.65		20.0	
Quiescent supply co	JI I CI I L	Icc	V _{CC} ≤ V _{IN} ≤ 3.6 V		1.4 to 1.65	_	±20.0	μΑ

DC Characteristics (Ta = -40 to 85° C, $1.2 \text{ V} \leq \text{V}_{CC} < 1.4 \text{ V}$)

Characteristics Symbol Test Cor		ndition	V _{CC} (V)	Min	Max	Unit			
	High level	V _{IH}	_	-	1.2 to 1.4	0.8 × V _{CC}	_		
Input voltage	Low level	V _{IL}	_		1.2 to 1.4	-	0.05 × V _{CC}	V	
Output voltage	High level	VoH	V _{IN} = V _{IH} or V _{IL}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -100 \mu\text{A}$		V _{CC} - 0.1	_	V	
	Low level	V _{OL}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 100 \mu\text{A}$		1.2	_	0.05		
Input leakage curren	it	I _{IN}	V _{IN} = 0 to 3.6 V		1.2	_	±5.0	μΑ	
Power off leakage co	urrent	loff	V _{IN} , V _{OUT} = 0 to 3.6 V		0	_	10.0	μΑ	
Quiescent supply current		loo	V _{IN} = V _{CC} or GND		1.2		20.0	μА	
Quiescent supply cu	Helit	Icc	V _{CC} ≤ V _{IN} ≤ 3.6 V		1.2	_	±20.0	μΑ	

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AC Characteristics (Ta = -40 to 85° C, Input: $t_r = t_f = 2.0$ ns) (Note 1)

Characteristics	Symbol Test Condition				Min	Max	Unit
Characteristics	Gyllibol	163	Condition	V _{CC} (V)	IVIIII	IVIAX	Onit
			$C_L = 15 pF, R_L = 2 k\Omega$	1.2	3.0	35.0	
Door on the order of the co			OL = 15 μι , NL = 2 ΚΩ	1.5 ± 0.1	2.0	14.0	
Propagation delay time (A, B-Y)	t _{pLH}	Figure 1, Figure 2		1.8 ± 0.15	1.5	7.0	ns
(A, D-1)	t _{pHL}		$C_L = 30 \text{ pF}, R_L = 500 \Omega$	2.5 ± 0.2	0.8	3.5	
				3.3 ± 0.3	0.6	3.0	
			$C_{I} = 15 pF, R_{I} = 2 k\Omega$	1.2	3.0	45.0	
Propagation delay time (SELECT-Y)			CL = 15 pr, RL = 2 KΩ	1.5 ± 0.1	2.0	18.0	
	t _{pLH}	Figure 1, Figure 2	$C_L = 30 \text{ pF}, R_L = 500 \Omega$	1.8 ± 0.15	1.5	9.0	ns
				2.5 ± 0.2	8.0	4.5	
				3.3 ± 0.3	0.6	3.5	
			$C_L = 15 \text{ pF}, R_L = 2 \text{ k}\Omega$	1.2	3.0	45.0	ns
Propagation dalay time	.			1.5 ± 0.1	2.0	18.0	
Propagation delay time (ST -Y)	t _{pLH}	Figure 1, Figure 2		1.8 ± 0.15	1.5	9.0	
(31-1)	t _{pHL}		$C_L = 30 \text{ pF}, R_L = 500 \Omega$	2.5 ± 0.2	8.0	4.5	
				3.3 ± 0.3	0.6	3.5	
			$C_L = 15 pF, R_L = 2 k\Omega$	1.2		1.5	
			OL = 13 μι , NL = 2 ΚΩ	1.5 ± 0.1		1.5	ns
Output to output skew	tosLH	(Note 2)	$C_L = 30$ pF, $R_L = 500 \Omega$	1.8 ± 0.15		0.5	
	t _{osHL}			2.5 ± 0.2		0.5	
				3.3 ± 0.3	_	0.5	

Note 1: For $C_L = 50\ pF$, add approximately 300 ps to the AC maximum specification.

Note 2: This parameter is guaranteed by design. $(t_{OSLH} = |t_{DLHm} - t_{DLHn}|, \, t_{OSHL} = |t_{DHLm} - t_{DHLn}|)$



Dynamic Switching Characteristics (Ta = 25°C, Input: $t_r = t_f$ = 2.0 ns, C_L = 30 pF)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
		$V_{IH} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ (No		0.25	
Quiet output maximum dynamic V _{OL}	V _{OLP}	V _{IH} = 2.5 V, V _{IL} = 0 V (No	e) 2.5	0.6	V
		V _{IH} = 3.3 V, V _{IL} = 0 V (No	e) 3.3	0.8	
	V _{OLV}	$V_{IH} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ (No.	e) 1.8	-0.25	
Quiet output minimum dynamic V _{OL}		$V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ (No.	e) 2.5	-0.6	V
		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ (No.	e) 3.3	-0.8	
	V _{OHV}	$V_{IH} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ (No.	e) 1.8	1.5	
Quiet output minimum dynamic V _{OH}		$V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ (No.	e) 2.5	1.9	V
		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ (No.	e) 3.3	2.2	

Note: This parameter is guaranteed by design.

Capacitive Characteristics (Ta = 25°C)

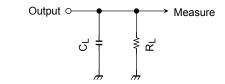
Characteristics	Symbol	Test Condition		V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}	_		1.8, 2.5, 3.3	6	pF
Power dissipation capacitance	C _{PD}	f _{IN} = 10 MHz	(Note)	1.8, 2.5, 3.3	20	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

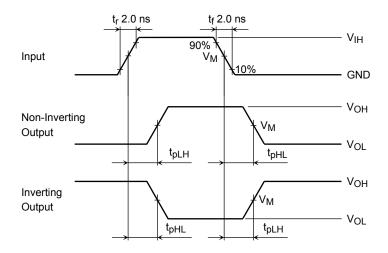
AC Test Circuit



	Vcc				
Symbol	$\begin{array}{c} 3.3 \pm 0.3 \text{ V} \\ 2.5 \pm 0.2 \text{ V} \\ 1.8 \pm 0.15 \text{ V} \end{array}$	1.5 ± 0.1 V 1.2V			
R_{L}	500 Ω	2 kΩ			
CL	30 pF	15 pF			

Figure 1

AC Waveform



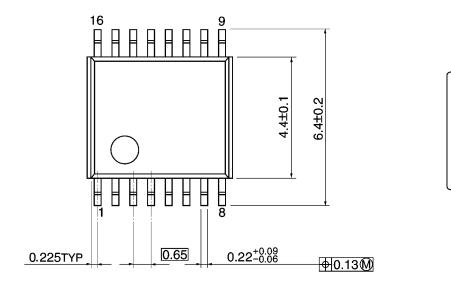
Symbol	Vcc				
	$3.3\pm0.3\;\text{V}$	$2.5\pm0.2\ V$	1.8 ± 0.15 V	$1.5\pm0.1\textrm{V}$	1.2 V
V _{IH}	2.7 V	V _{CC}	V _{CC}	V _{CC}	V _{CC}
V _M	1.5 V	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2

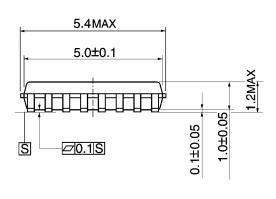
Figure 2 t_{pLH}, t_{pHL}

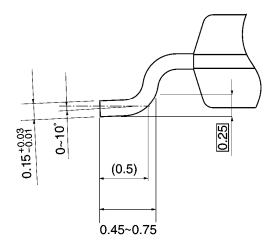
Package Dimensions

TSSOP16-P-0044-0.65A

Unit: mm



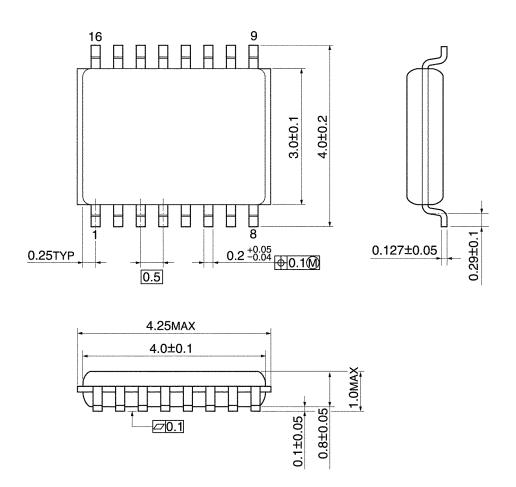




Weight: 0.06 g (typ.)

Package Dimensions

VSSOP16-P-0030-0.50 Unit: mm



Weight: 0.02 g (typ.)

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